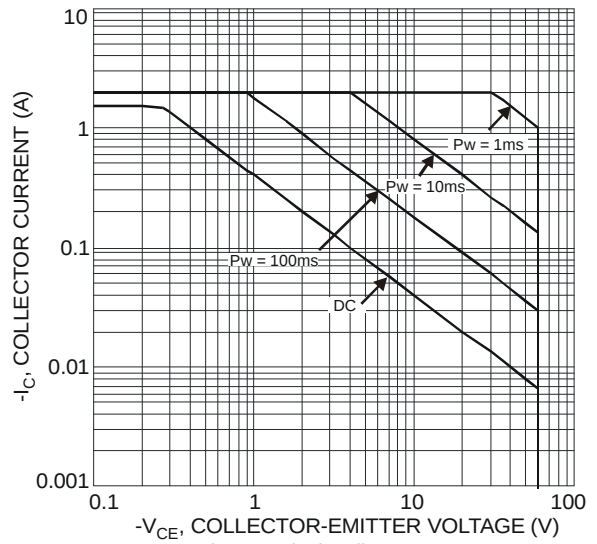
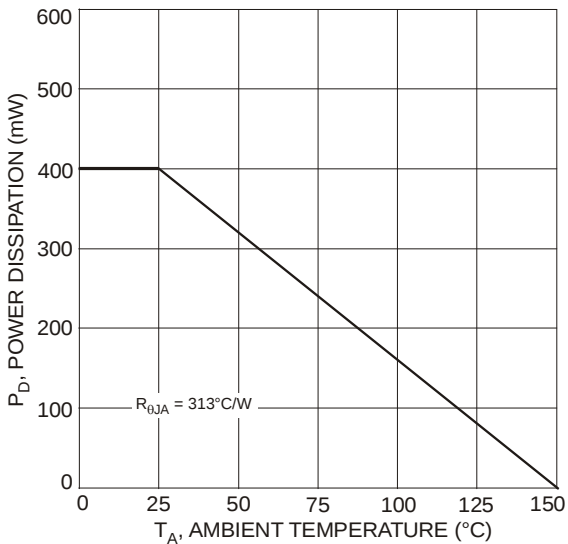


Electrical Characteristics @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	V _{(BR)CBO}	-80	—	—	V	I _C = -100μA, I _E = 0
Collector-Emitter Breakdown Voltage (Note 4)	V _{(BR)CEO}	-60	—	—	V	I _C = -10mA, I _B = 0
Emitter-Base Breakdown Voltage	V _{(BR)EBO}	-5	—	—	V	I _E = -100μA, I _C = 0
Collector Cutoff Current	I _{CBO}	—	—	-100 -50	nA μA	V _{CB} = -60V, I _E = 0 V _{CB} = -60V, I _E = 0, T _A = 150°C
Collector Cutoff Current	I _{CES}	—	—	-100	nA	V _{CE} = -60V, V _{BE} = 0
Emitter Cutoff Current	I _{EBO}	—	—	-100	nA	V _{EB} = -5V, I _C = 0
ON CHARACTERISTICS (Note 4)						
DC Current Gain	h _{FE}	200 150 100	— — —	— — —	—	V _{CE} = -5V, I _C = -1mA V _{CE} = -5V, I _C = -500mA V _{CE} = -5V, I _C = 1A
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	— — —	— — —	-175 -180 -340	mV	I _C = -100mA, I _B = -1mA I _C = -500mA, I _B = -50mA I _C = -1A, I _B = -100mA
Collector-Emitter Saturation Resistance	R _{CE(SAT)}	—	—	340	mΩ	I _C = -1A, I _B = -100mA
Base-Emitter Saturation Voltage	V _{BE(SAT)}	—	—	-1.1	V	I _C = -1A, I _B = -50mA
Base-Emitter Turn On Voltage	V _{BE(ON)}	—	—	-0.9	V	V _{CE} = 5V, I _C = 1A
SMALL SIGNAL CHARACTERISTICS						
Output Capacitance	C _{obo}	—	—	15	pF	V _{CB} = -10V, f = 1.0MHz
Current Gain-Bandwidth Product	f _T	150	—	—	MHz	V _{CE} = -10V, I _C = -50mA, f = 100MHz
SWITCHING CHARACTERISTICS						
Turn-On Time	t _{on}	—	75	—	ns	V _{CC} = -10V I _C = -0.5A, I _{B1} = I _{B2} = -25mA
Delay Time	t _d	—	35	—	ns	
Rise Time	t _r	—	40	—	ns	
Turn-Off Time	t _{off}	—	265	—	ns	
Storage Time	t _s	—	230	—	ns	
Fall Time	t _f	—	35	—	ns	

Notes: 4. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤2%.



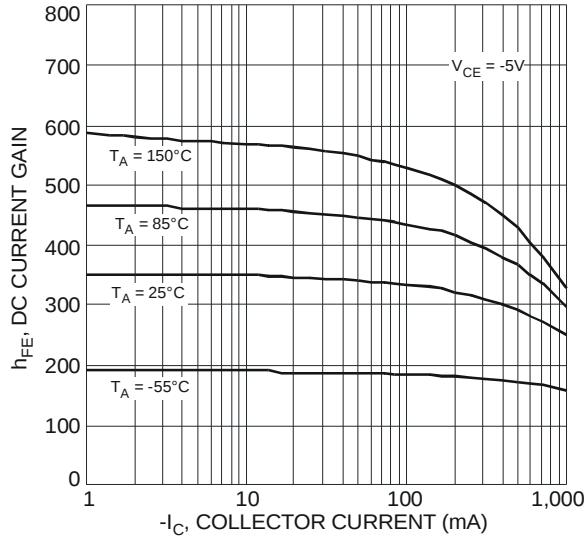


Fig. 3 Typical DC Current Gain vs. Collector Current

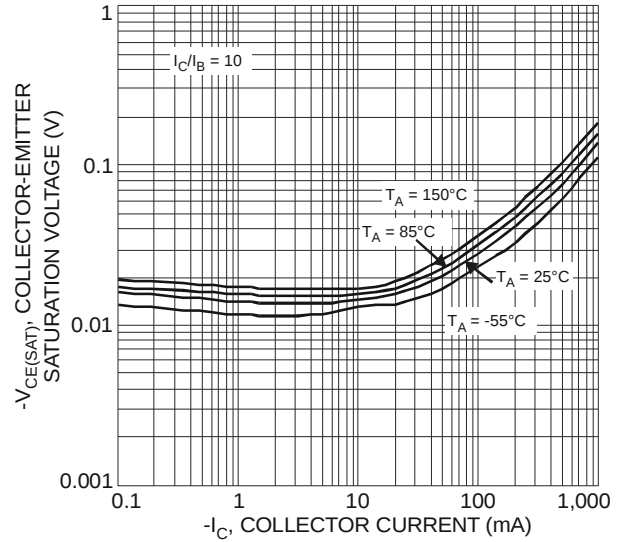


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

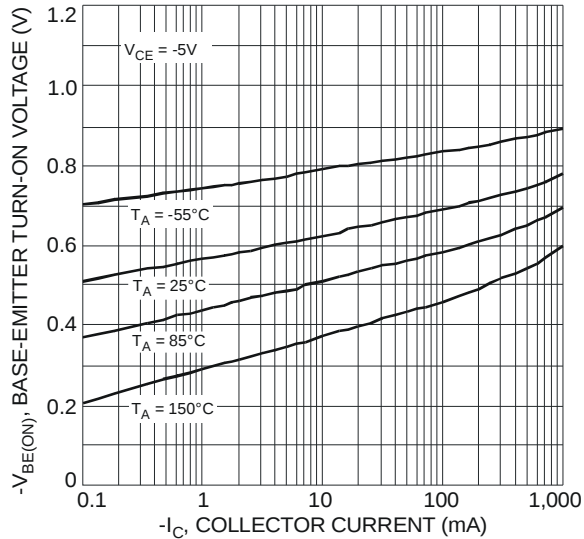


Fig. 5 Typical Base-Emitter Turn-On Voltage vs. Collector Current

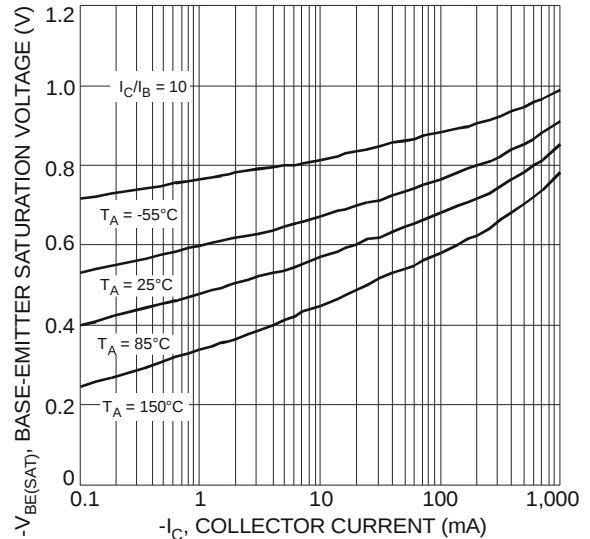


Fig. 6 Typical Base-Emitter Saturation Voltage vs. Collector Current

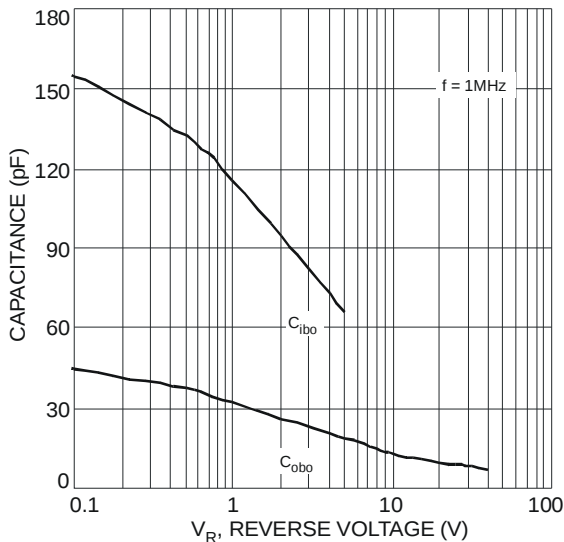


Fig. 7 Typical Capacitance Characteristics

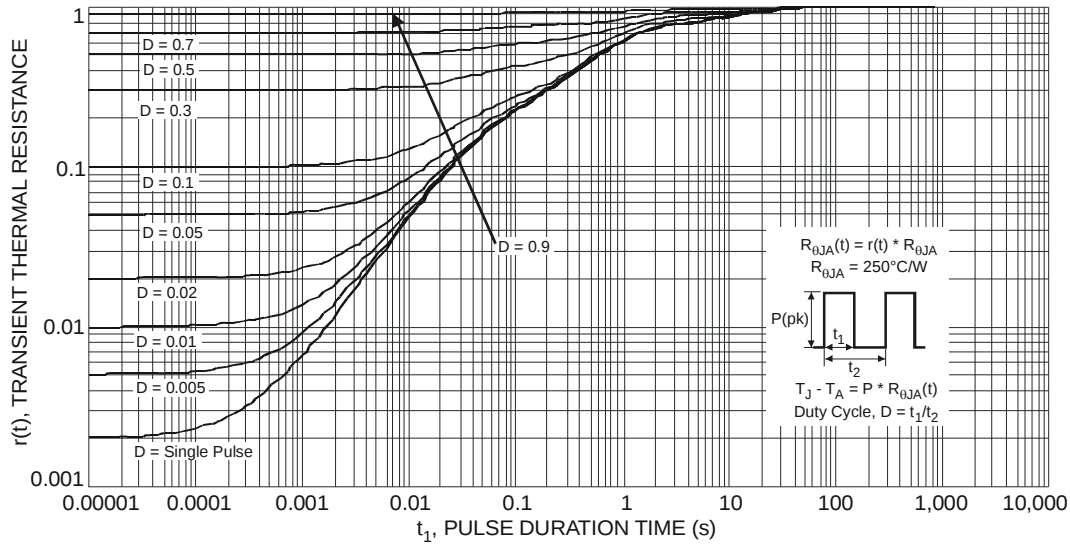


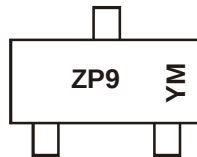
Fig. 8 Transient Thermal Response (Note 3)

Ordering Information (Note 5)

Part Number	Case	Packaging
DSS5160U-7	SOT-323	3000/Tape & Reel

 Notes: 5. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

Marking Information



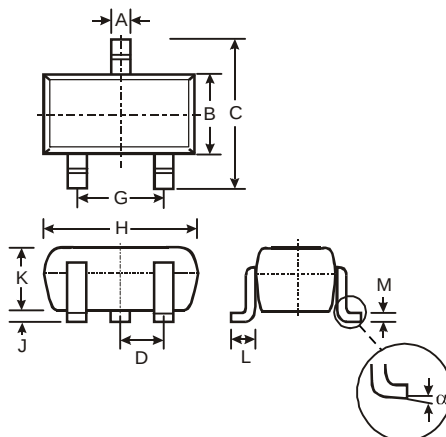
ZP9 = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: V = 2008)
 M = Month (ex: 9 = September)

Date Code Key

Year	2008	2009	2010	2011	2012	2013	2014	2015
Code	V	W	X	Y	Z	A	B	C

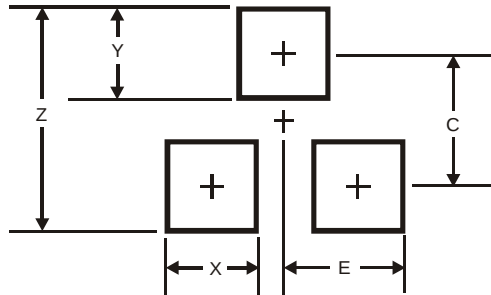
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Package Outline Dimensions



SOT-323			
Dim	Min	Max	Typ
A	0.25	0.40	0.30
B	1.15	1.35	1.30
C	2.00	2.20	2.10
D	-	-	0.65
G	1.20	1.40	1.30
H	1.80	2.20	2.15
J	0.0	0.10	0.05
K	0.90	1.00	1.00
L	0.25	0.40	0.30
M	0.10	0.18	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	2.8
X	0.7
Y	0.9
C	1.9
E	1.0

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